



Influence of TiO₂ particle size and conductivity of the CuCrO₂ nanoparticles on the performance of solid-state dye-sensitized solar cells

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Abstract. Solid-state dye-sensitized solar cells have been fabricated with mesoporous TiO₂ photoanode and N719 dye as photosensitizer. First, TiO₂ and non-doped, Zn- and Mg-doped CuCrO₂ nanoparticles have been synthesized by sol–gel method. In addition, the TiO₂ pastes have been prepared through Pechini-type sol–gel method. The effect of TiO₂ particle size, mesoporous TiO₂ photoanode thickness and solid-state electrolyte thickness on the efficiency of the fabricated devices has been investigated. Our results show that in spite of the low amount of dye loading for photoanode with large TiO₂ nanoparticles (80–180 nm), the dye-sensitized solar cell made from it has higher efficiency than that constructed from the photoanode comprising of small particles about 10–15 nm in size. The higher efficiency is attributed to the longer diffusion length of electrons because of a better electron transport and penetration of a large amount of CuCrO₂ nanoparticles in the porous structure of TiO₂ photoanode. By using the doped CuCrO₂ nanoparticles, the efficiency has been increased from 0.027% for TiO₂/N719 dye/CuCrO₂ to 0.033% for TiO₂/N719 dye/CuCrO₂:Zn and further increased to 0.042% for TiO₂/N719 dye/CuCrO₂:Mg. The efficiency enhancement by doping is ascribed to the conductivity improvement due to the presence of impurity atoms.

Keywords. Solid-state dye-sensitized solar cells; sol–gel method; TiO₂ nanoparticle; CuCrO₂ nanoparticles; electrical transport.

1. Introduction

Dye-sensitized solar cells (DSSCs) have attracted great attention over the past decade due to high-energy conversion efficiency, simple manufacturing process and low production cost [1–4]. Transparent conductive oxides as substrate, mesoporous metal oxide semiconductor thick films, dye sensitizers, electrolytes and counter electrodes are the main components of a typical DSSC [5–8]. Recently, the highest conversion efficiency of a TiO₂-based DSSC has been reported by using molecularly engineered porphyrin dye, coded SM315 and an organic liquid-based electrolyte containing cobalt (II/III) redox couple [9]. However, the leakage and evaporation of the organic solvent in the liquid electrolyte has been a serious challenge for long-term practical applications, especially under elevated temperature condition [10,11]. The leakage of toxic organic solvents and evaporation of volatile iodine ions in liquid electrolyte reduces the charge carrier concentration. The reduction in charge carrier concentration increases the overall internal resistance and finally the efficiency of the device is decreased. Many efforts have been made to overcome this problem and it has been found that instead of liquid electrolyte the use of solid-state electrolytes, such as polymer electrolytes, which are defined as polymer materials

complexed with salts, plastic crystal electrolytes, inorganic p-type semiconductors, organic hole conductors and room temperature molten salts can be effective [12–14]. Nevertheless, energy conversion efficiency of the fabricated devices with these solid-state electrolytes is not usually satisfactory. The low conversion efficiency is mainly attributed to the low ionic conductivity of the electrolyte and/or poor electrode/electrolyte interfacial contact [15].

To date, several inorganic copper-based compounds such as CuI, CuBr and CuSCN have been used as inorganic hole transfer materials (HTMs) because of their good conductivity and appropriate band positions but they are unstable and tend to degrade quickly [16–19]. Hence, finding a suitable inorganic p-type semiconductor with desired properties such as appropriate band gap, band positions and a method for its deposition is a great challenge. Wide band-gap p-type oxide semiconductors can be regarded as suitable candidates for inorganic HTMs because of their good conductivity, stability and appropriate band positions [15]. Previously, Bandara and Weerasinghe [20] have reported the use of NiO nanoparticles as an inorganic HTM in TiO₂-based DSSCs. In 2007, the photovoltaic parameters of the solid-state DSSCs utilizing CuAlO₂ nanoparticles in TiO₂/N719 dye/CuAlO₂ structure have been reported by Bandara and Yasomanee [21].

Then, Lee *et al* [22,23] prepared n-TiO₂/p-NiO heterojunction electrodes for all-solid-state DSSCs. Numerous delafossite oxides (CuAlO₂, CuGaO₂ and CuCrO₂) have also been utilized to serve as photocathode materials in p-type DSSCs in replacement of conventional NiO; but their reported efficiencies are much lower than those of n-type DSSCs. The energy conversion efficiency of p-type DSSCs with small size CuAlO₂ particles (35 nm), was reported to be around 0.037% [24]. Xiong *et al* [6] have reported an overall power conversion efficiency of 0.132% with CuCr_{0.9}Mg_{0.1}O₂ dye-sensitized photocathode under optimized conditions, but with P1 dye. On the other hand, Renaud *et al* [25] have investigated the effect of Mg doping on the photovoltaic performance of CuGaO₂-based p-type DSSCs and achieved a maximum efficiency of 0.045%.

The purpose of this work is construction and optimization of TiO₂/N719 dye/CuCrO₂ solid-state DSSCs. We study the effect of TiO₂ particle size on the efficiency of the fabricated devices. The thickness of the TiO₂ photoanode and the solid-state electrolyte is also important to enhance its efficiency. For further improvement, we use doped CuCrO₂ nanoparticles. Addition of divalent cations in the CuCrO₂ lattice can increase the p-type conductivity and thus can influence the efficiency of the solid-state DSSCs.

2. Experimental

The TiO₂ nanoparticles with two distinct diameters of about 10–15 and 80–180 nm in the anatase phase were synthesized from titanium tetraisopropoxide (TTIP, Samchun Chemical Co., Korea), hydrochloric acid (HCl, Ameretat Co., Iran), anhydrous alcohol (Merck Co., Germany) and distilled water by sol-gel method. Initially, 10 ml of TTIP was dissolved in 10 ml anhydrous alcohol (ethanol) and stirred to obtain a clear solution. Then, 5 ml of distilled water was slowly added into the solution, which was stirred for 2 h at room temperature. The pH value of the solution was adjusted at 2.0 by dropwise addition of 0.1 M hydrochloric acid with vigorous stirring. The resultant solution was aged for 24 h at room temperature. After that the obtained precursor was washed several times with distilled water and anhydrous alcohol and dried at 100°C for 12 h. Finally, the dried powders were annealed at 400 and 600°C for 3 h in a laboratory electric furnace (Azar Furnace Co., Model F35L-1200, Iran). Heat treatment at different temperatures will lead to different particle sizes.

The sol-gel method was similarly employed for synthesis of CuCrO₂ nanoparticles. We used copper acetate monohydrate (Cu(CH₃COO)₂ · H₂O, Merck Co., Germany) and chromium nitrate nonahydrate (Cr(NO₃)₃ · 9H₂O, Merck Co., Germany) as starting materials and 2-methoxyethanol (CH₃(CH₂)₂OOH, Merck Co., Germany) as a solvent. Furthermore, zinc acetate dihydrate (Zn(CH₃COO)₂ · H₂O, Merck Co., Germany) and magnesium nitrate hexahydrate (Mg(NO₃)₂ · 6H₂O, Merck Co. Germany) were used as

dopant sources. The precursor solutions were prepared by dissolving copper acetate monohydrate and chromium nitrate nonahydrate in 2-methoxyethanol at 60°C. In order to fabricate the metal-doped CuCrO₂ nanoparticles, zinc acetate dihydrate and magnesium nitrate hexahydrate were added to the precursor solution. The copper acetate/chromium nitrate molar ratio was fixed at 1:1. The concentration of copper acetate in the initial solutions was kept to be 0.7 M and the concentration of Zn and Mg as dopants was 5% with respect to Cr in the solutions. The prepared precursor solutions were stirred at 60°C for 3 h to yield clear, homogenous and deep green solutions. The obtained solutions were dried at 110°C for 3 h. Finally, the dried powders were annealed in air at 900°C for 1 h in the furnace.

The TiO₂ pastes were prepared by Pechini-type sol-gel method [26,27]. To fabricate DSSCs, F-doped SnO₂(FTO) conducting glass substrates were first cleaned in ethanol and acetone solution using an ultrasonic bath for 10 min and then rinsed with ethanol. The TiO₂ pastes were coated on cleaned FTO conducting glasses by spin coating method (using a Backer Viera Trading SC-410 spin-coater, Iran). The TiO₂ mesoporous films were aged at room temperature for 15 min and then sintered at 450°C for 1 h in a laboratory electric furnace (Azar Furnace Co., Model F35L-1200, Iran). Subsequently, the sintered TiO₂ mesoporous films were immersed into 0.4 mM ethanol solution of N719 dye for 24 h to allow for sufficient dye adsorption. Then, the films were rinsed with anhydrous ethanol and finally dried at the ambient condition. In this way, the dye-sensitized TiO₂ electrodes were obtained. In order to deposit the CuCrO₂ nanoparticles on the dye-sensitized TiO₂ electrode, the p-type nanoparticles were dispersed in ethanol solution. The solution of CuCrO₂ nanoparticles was carefully deposited on the mesoporous TiO₂ electrode by the spin coating technique. The CuCrO₂ solid-state electrolyte thickness was controlled by the speed of rotation. The platinumized conducting glass electrode was prepared by H₂PtCl₆ solution (5 mM in 2-propanol) on a clean FTO substrate by sol-gel spin coating technique (500 rpm for 10 s). The precursor film was first dried at 150°C and then the obtained film was annealed at 450°C for 30 min. Then, the Pt electrode was placed over the dye-adsorbed TiO₂ electrode and the two electrodes were held with a binder clip.

The phase and crystal structure of the synthesized nanoparticles were identified by X-ray diffraction (XRD) with a PANalytical X'Pert Pro powder diffractometer with Cu K α = 1.5406 Å radiation. The particle size and the thickness of the TiO₂ and CuCrO₂ layers were analysed using field emission scanning electron microscopy (FESEM) (TESCAN mira 3 xmu) and cross-sectional scanning electron microscopy (HITACHI S-4160 SEM), respectively. The amount of the N719 dye adsorbed on the TiO₂ mesoporous photoanode, which is related to the active surface area of the TiO₂ layer, was determined with 3648 UV-Vis Avantes spectrophotometer. We inspected the performance of the fabricated DSSCs by recording the current-voltage curve with computer-controlled digital source metre (Sharif Solar, IV-25) and a solar simulator

(AM 1.5G, Sharif Solar, SIM-1000) as a light source calibrated to 100 mW cm^{-2} with a standard Si solar cell. Hall effect and resistivity measurements were carried out by employing the van der Pauw configuration. The magnetic field in Hall effect measurements was fixed at 400 mT.

3. Results and discussion

Figure 1a shows the XRD patterns of the synthesized TiO_2 nanoparticles heat-treated at different temperatures for 3 h. XRD studies show that the synthesized TiO_2 nanoparticles are in pure anatase phase, and the crystal structures agree with the corresponding JCPDS data (JCPDS Card No. 21-1272). High purity and crystallinity of the synthesized TiO_2 particles are revealed by the appearance of clear and sharp peaks. The results show that the intensity of the peaks moderately increases with annealing temperature. The crystallite size of the prepared TiO_2 nanoparticles at 400 and 600 °C were estimated by Debye–Scherrer equation to be about 9.3 and 14.6 nm, respectively [28]. The results are in agreement with other literature [29]. Similarly, XRD patterns of synthesized CuCrO_2 nanoparticles are shown in figure 1b. The diffraction peaks in the figure are indexed to the delafossite-type phase of CuCrO_2 nanoparticles (JCPDS Card No. 89-6744) with a rhombohedral unit cell. These results indicate that highly crystalline and single phase CuCrO_2 nanoparticles have been synthesized with 5% Mg and Zn dopants. The estimated crystallite size in the preferential direction is about 32.3, 29.8 and 28.7 for undoped, Zn- and Mg-doped CuCrO_2 nanoparticles, respectively.

In conjunction with the crystallite size growth, the size of the nanoparticles can also be increased with annealing temperature. In figure 2, FESEM images of TiO_2 nanoparticles show that the size of the fabricated TiO_2 nanoparticles is in the range of 10–15 nm (sample A) and 80–180 nm (sample B), respectively. Figure 3a shows the J – V characteristics of both the solar cells consisting of TiO_2 photoanodes with different particle sizes (with the same thickness of about $10 \mu\text{m}$) and undoped CuCrO_2 nanoparticles as solid-state electrolyte (with thickness of about $3.5 \mu\text{m}$). The short-circuit current density (J_{SC}) and open-circuit voltage (V_{OC}) of sample B are 0.127 mA cm^{-2} and 215 mV, respectively, which are higher than those of sample A (0.058 mA cm^{-2} and 170 mV), leading to a significant enhancement of efficiency (0.010% compared to 0.0037% for sample A). It is well known that the TiO_2 photoanode constructed from the smaller particles has greater surface area than that having larger particles [30] and therefore, the amount of the adsorbed dye by the TiO_2 photoanode fabricated with small particles is more [31]. UV–Vis absorption spectra of desorbed N719 dye from the TiO_2 photoanode confirms our statement about the amount of adsorbed dye on the surface of nanoparticles (figure 3b). To perform this analysis, we collected the desorbed N719 dye from TiO_2 photoanode by immersing the TiO_2 photoanode in 0.05 M NaOH in an ethanol and water aqueous solution with 1:1 volume

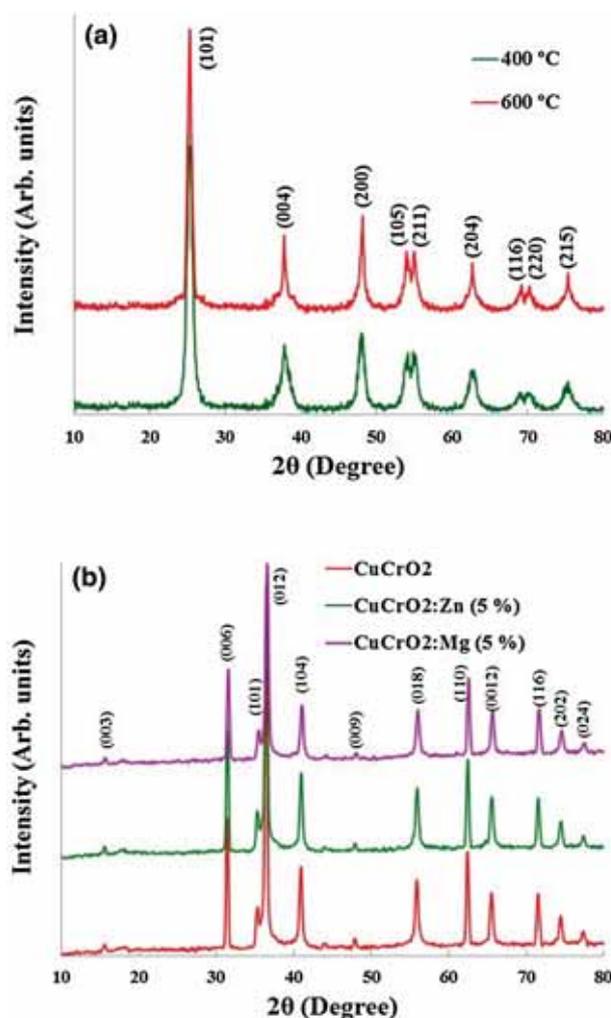


Figure 1. XRD patterns of synthesized (a) TiO_2 nanoparticles and (b) undoped, Zn- and Mg-doped CuCrO_2 nanoparticles.

ratio [32]. On the other hand, as can be seen in literature, TiO_2 photoanodes fabricated with small-size particles have dense layer and good adherence to FTO substrate [26]. For these reasons, the short-circuit current density and the efficiency of DSSCs fabricated using small particles should be higher than those comprising large particles. However, in our case, the DSSC fabricated with the photoanode B, which consists of TiO_2 particles with a size of about 80–180 nm has higher short-circuit current density and efficiency than the DSSC made from the photoanode A, with the same TiO_2 thickness. Our results show that the TiO_2 mesoporous layers prepared using small and large TiO_2 nanoparticles are difficult to detach from the surface of the FTO glasses. The adherence of TiO_2 particles in both the cases is the same and their good adherence to the FTO glasses are in agreement with results reported by Hocevar *et al* [26,33]. As a result, in our case, the amount of adsorbed dye on the surface of nanoparticles and the adherence of TiO_2 nanoparticles to FTO glasses have no predominant effect on the J_{SC} increment. The J_{SC} increment can be attributed to the electron transport mechanism.

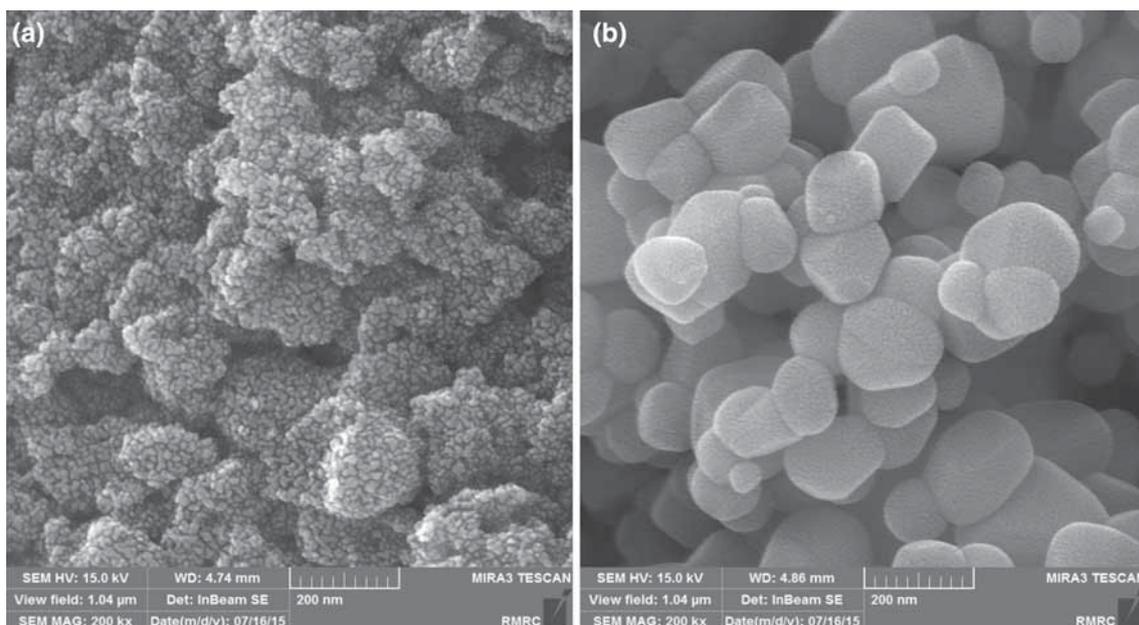


Figure 2. FESEM images of the prepared (a) small-size and (b) large-size TiO_2 nanoparticles.

A two-step carrier transport mechanism is mentioned for the electron in TiO_2 photoanode. First, electrons diffuse inside one particle and after reaching the surface of the particle they transfer from the particle to the neighbouring one through a neck formed between them. From this vision, larger semiconductor particles and larger neck size are desirable for good electron transport [34,35]. In 2003, Nakade *et al* [36] showed that the photoanode fabricated with larger TiO_2 nanoparticles has suitable resistance to prevent recombination as a result of the longer diffusion length of electrons in the TiO_2 nanoparticle film. The increment in diffusion length is attributed to the reduced boundaries such as grain boundary. On the other hand, TiO_2 photoanode fabricated with small particles has a nanoporous structure in comparison with that made from large ones. Difficulty in penetration of solid-state electrolyte in nanoporous structure of TiO_2 photoanode increases the electron-hole recombination in DSSCs. Therefore, although TiO_2 photoanode fabricated with the large-size particles does not have a large surface area for dye adsorption, but the good electron transport and penetration of the large amount of CuCrO_2 nanoparticles in the porous structure lead to higher short-circuit current density. The increment in open-circuit voltage can be attributed to the reduction in the electron-hole recombination, which can be concluded from fill factor and open-circuit voltage decay measurement. Open-circuit voltage decay measurement is used as a simple and powerful method to study the rate of electron recombination in DSSCs [37]. Zaban *et al* [38] suggested that the rate of open-circuit voltage decay is inversely related to the lifetime of the light-generated electron in DSSCs and that the lifetime of the electron is inversely related to the rate of recombination. The relationship between voltage decay and charge carrier lifetime

is given in equation (1) [38]:

$$\tau_n = \frac{k_B T}{q} \left(\frac{dV_{oc}}{dt} \right)^{-1},$$

in which k_B is the Boltzmann constant, T is the absolute temperature and q is the positive elementary charge. To measure the open-circuit voltage decay, the simulated solar light is turned off and the decay of photovoltage is recorded. Figure 3c shows the open-circuit voltage decay of the fabricated DSSCs. As can be seen, the decay of the photovoltage for sample A is faster than that of sample B, which indicates that the recombination rate is faster in sample A in comparison with the other one. Consequently, the enhancement of efficiency is obtained for the TiO_2 photoanode fabricated by using the larger particles. The electron lifetimes determined from the open-circuit voltage decay measurements are about 5.1 ms for small nanoparticles and 6.9 ms for large nanoparticles at open-circuit voltage (see figure 3d).

To increase the power conversion efficiency we search for the optimal thickness of the photoanode. The thickness of the TiO_2 photoanode is controlled by the speed of spin-coating and its value is measured by cross-sectional FESEM (micrographs are not shown). DSSCs fabricated with thin TiO_2 layers have low efficiency due to the small amount of adsorbed dye on the surface of mesoporous layer [39]. On the other hand, DSSCs fabricated with thick TiO_2 photoanodes have low efficiency due to the recombination phenomena originated from the difficulty in collection of electron because of long distance. Similar problems can happen for solid-state DSSCs as well. Figure 4a displays the $I-V$ characteristic of fabricated DSSCs with different thicknesses. As can be seen, the

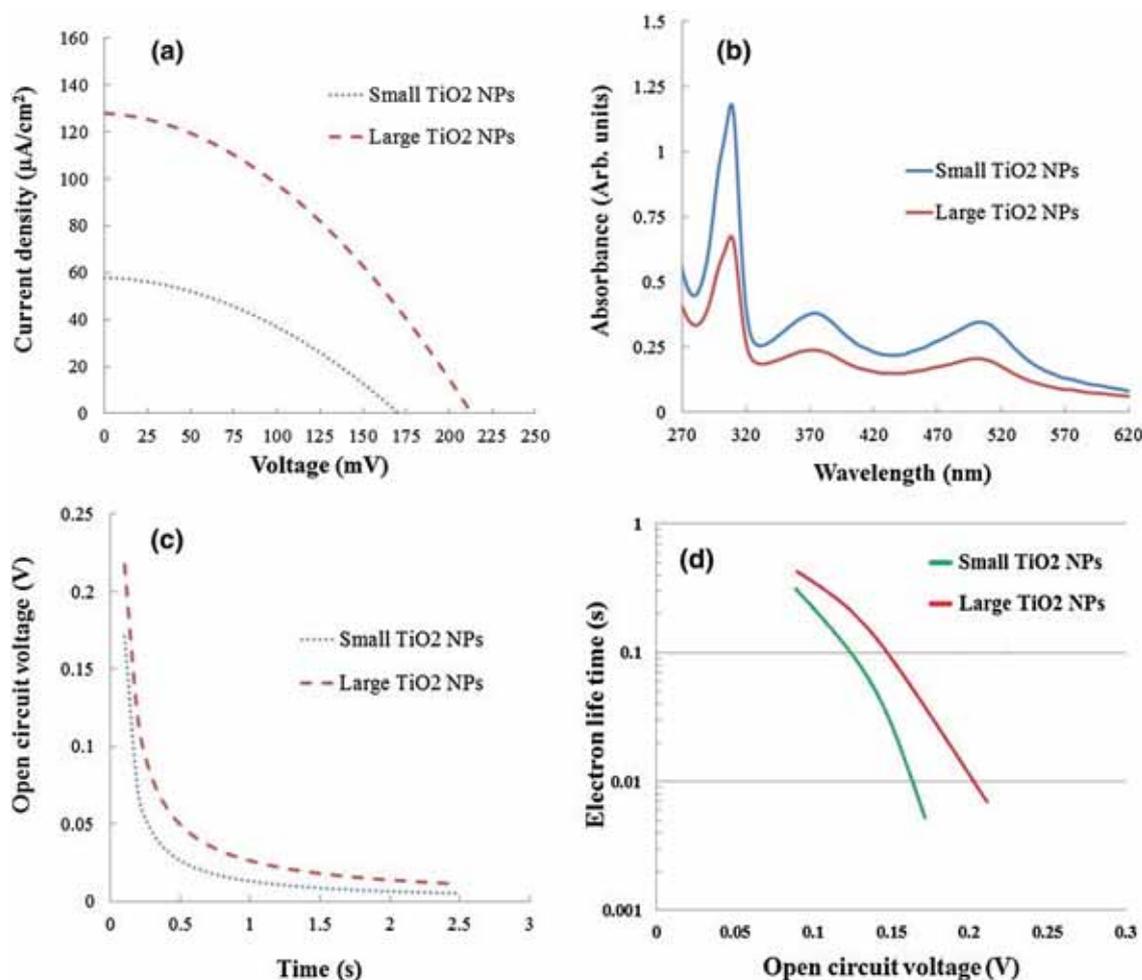


Figure 3. (a) Current density–voltage characteristics of the DSSCs fabricated using TiO₂ particles with two different sizes, (b) absorbance spectra of NaOH solution containing dye molecules desorbed from TiO₂ photoanodes, (c) open-circuit voltage (V_{OC}) decay of the fabricated DSSCs and (d) calculated electron lifetime as a function of open-circuit voltage.

value of the short-circuit current density increases with the TiO₂ layer thickness up to 21 μm and then slightly decreases. As the thickness of the TiO₂ mesoporous layer increases, the amount of adsorbed dye on the surface of the mesoporous layer increases, which in turn can enhance the number of electron-hole pairs. UV–Vis absorption spectra of desorbed N719 dye from the TiO₂ photoanodes with different thicknesses are shown in figure 4b. Initially, the light-generated carriers can easily be collected at the thinnest photoanode, but J_{SC} is low due to the small amount of adsorbed dye. For the thickest photoanode, the generated electrons cannot easily be moved to the electron collector. The long distance and recombination of electron-hole pairs are the predominant factors for the reduction of J_{SC} . As a result, the highest values of J_{SC} and efficiency are obtained for the thickness of TiO₂ layer of around 21 μm . The open-circuit voltage decay measurement shows faster recombination rate for the DSSC fabricated with thickness of about 37 μm (see figure 4c). At

open-circuit voltage, the derived electron lifetimes from the open-circuit voltage decay measurements are about 6.9, 15.2 and 8.3 ms for 10, 21 and 37 μm thick TiO₂ photoanodes, respectively.

In the later step, we study the effect of CuCrO₂ thickness and Mg and Zn doping in CuCrO₂ as a solid-state electrolyte. Owing to the difficulty in preparation of bi-layer samples for cross-sectional SEM analysis (a layer of CuCrO₂ nanoparticles on the TiO₂ paste), we deposited the CuCrO₂ nanoparticles on glass substrate in the same condition for preparing the DSSCs and measured their thicknesses (micrographs are not shown). Current–voltage characteristics of the fabricated DSSCs with different thicknesses of solid-state electrolyte are displayed in figure 5a. The results indicate that the efficiency of DSSCs decreases with increase in thickness of CuCrO₂ above 4.7 μm . The reduction in the efficiency of DSSCs may be due to increase in resistivity of CuCrO₂ nanoparticles, which is originated from carrier scattering from

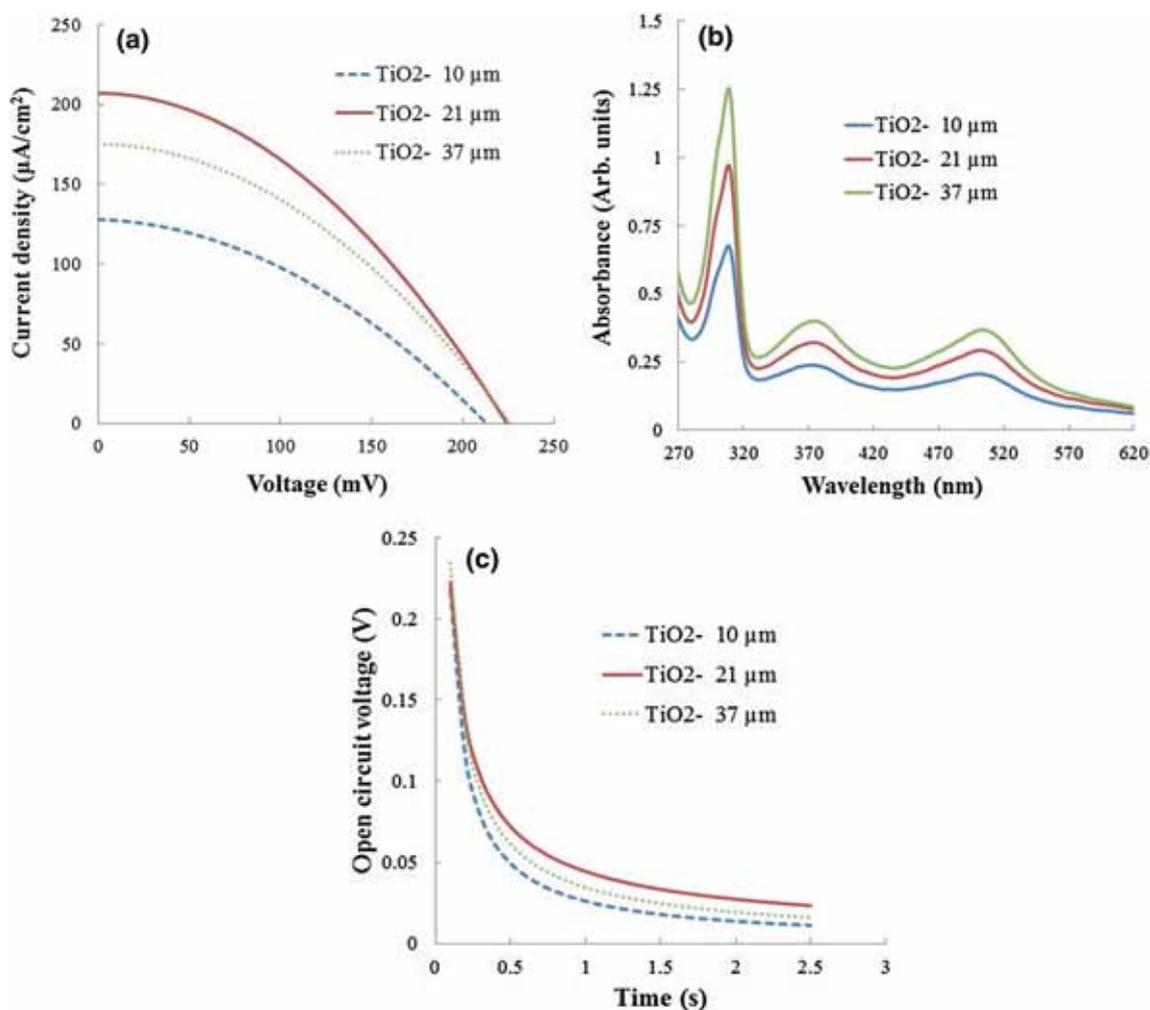


Figure 4. (a) Current density–voltage characteristics of the DSSCs with different thicknesses of TiO₂ photoanode, (b) absorbance spectrum of NaOH solution containing dye molecules, which were desorbed from TiO₂ photoanodes and (c) decay of the open-circuit voltage (V_{OC}) of the DSSCs with different thicknesses of the TiO₂ layer.

particle boundaries. Figure 5b shows the open-circuit voltage decay measurement of the fabricated DSSCs. As can be seen, the decay of voltage in the DSSC with 6.5 μm thick of CuCrO₂ solid-state electrolyte is faster than the two others, which indicates that the recombination rate in this DSSC is faster when compared with the others. At open-circuit voltage, the calculated electron lifetimes from the open-circuit voltage decay measurements are about 15.2, 21.3 and 10.3 ms for 3.5, 4.7 and 6.5 μm thick CuCrO₂ solid-state electrolyte, respectively.

The current–voltage characteristics of DSSCs for different types of CuCrO₂ solid-state electrolytes are shown in figure 6a. Among the constructed devices the TiO₂/N719 dye/CuCrO₂ solid-state DSSC shows the lowest conversion efficiency, about 0.027%, and the lowest fill factor of 35%. The J_{SC} is 316 $\mu\text{A cm}^{-2}$ and V_{OC} is around 0.242 V. From table 1, we can realize an efficiency increase from 0.027% for TiO₂/N719 dye/CuCrO₂ to 0.033% for TiO₂/N719 dye/CuCrO₂:Zn and further increase to 0.042%

for TiO₂/N719 dye/CuCrO₂:Mg. It is noteworthy to see that the doping improves J_{SC} , V_{OC} and the efficiency of DSSCs. The increase in J_{SC} can be attributed to the conductivity enhancement of CuCrO₂ nanoparticles. When a small amount of divalent cation is introduced into the CuCrO₂ lattice and is placed in the Cr³⁺ site, electrical conductivity is improved due to the creation of one free-hole. The Hall effect measurement results indicate that the Mg-doped CuCrO₂ nanoparticles have large carrier concentration and conductivity in comparison with Zn-doped CuCrO₂ nanoparticles at the same dopant concentration (see table 2). The impurity doping also increases the open-circuit voltage. This increase of V_{OC} may be explained by the difference in the work function of metal-doped CuCrO₂ and that of the non-doped one. The CuCrO₂ nanoparticles with Mg doping have a larger work function resulting from a larger hole carrier concentration. With addition of acceptor dopant, the Fermi level (E_f) moves towards valence-band edge. In this case, the work function $\phi = E_\infty - E_f$ (where

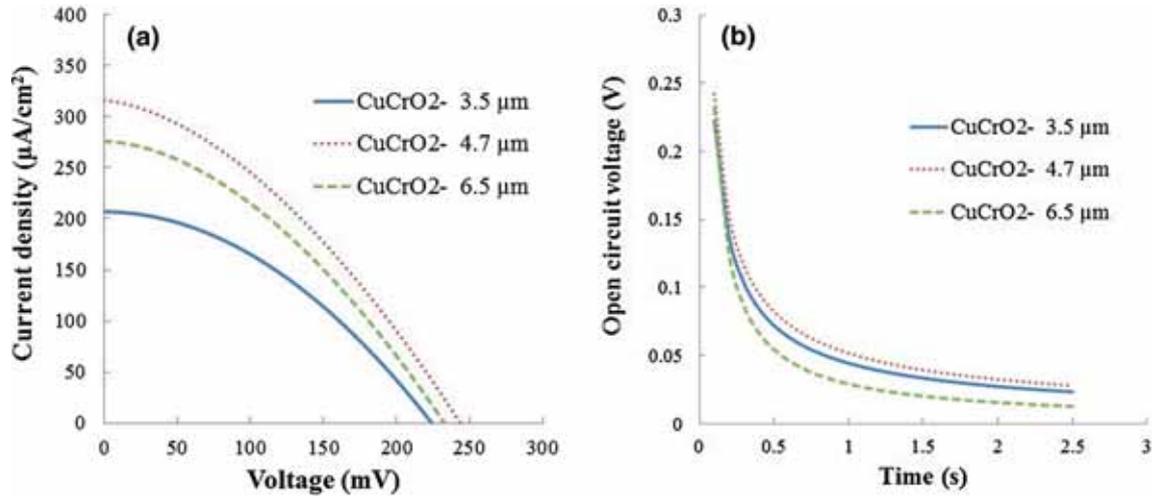


Figure 5. (a) Current density–voltage characteristics and (b) open-circuit voltage decay of the DSSCs with different thicknesses of CuCrO_2 hole transport layer.

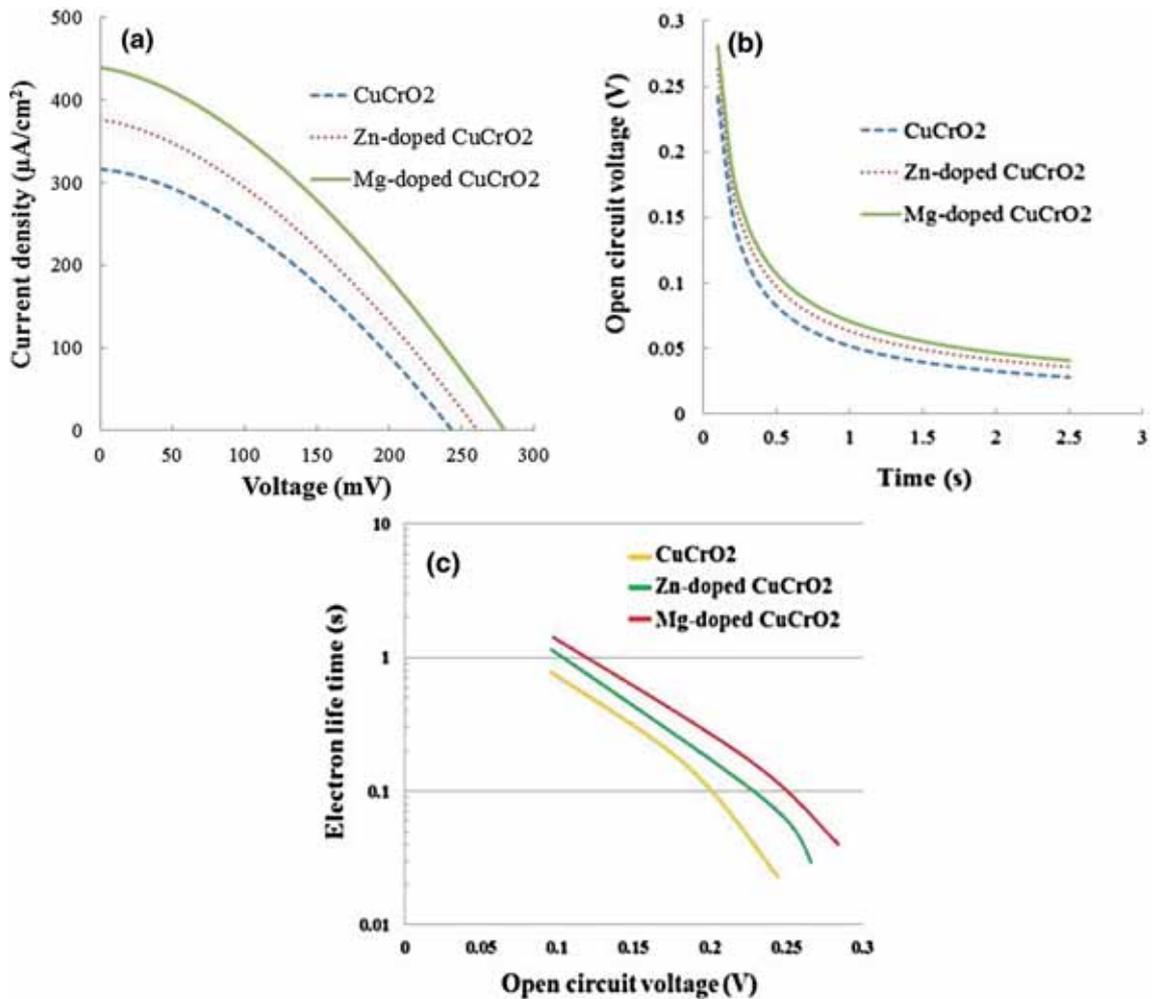


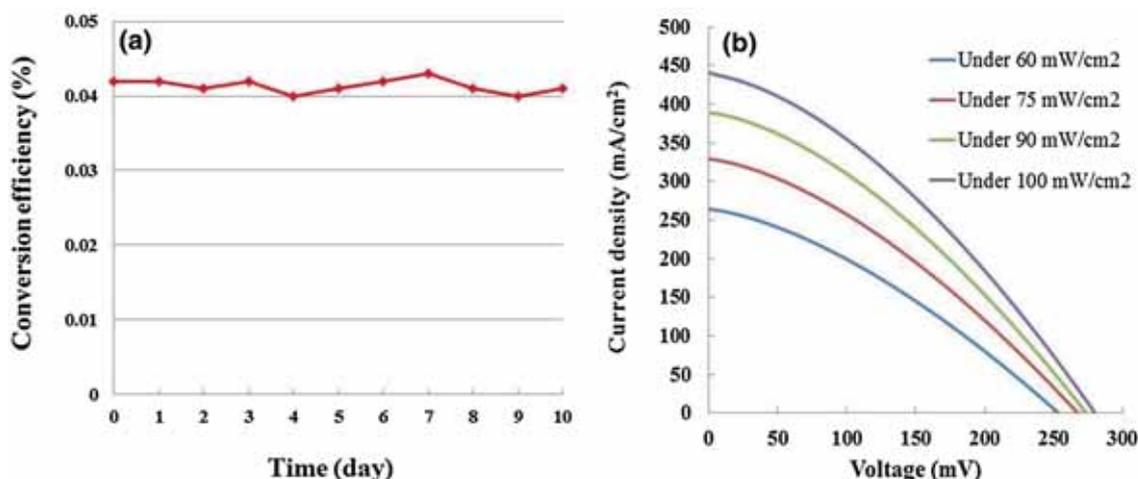
Figure 6. (a) current density–voltage (J – V) plots of cells made from non-doped, Zn- and Mg-doped CuCrO_2 nanoparticles as solid-state electrolytes, (b) open-circuit voltage decay vs. time for different solid-state DSSCs and (c) calculated electron lifetime as a function of open-circuit voltage.

Table 1. Photovoltaic parameters of the solid-state DSSCs with different dopants in CuCrO₂ hole transport layers.

Sample	FF (%)	J_{SC} ($\mu\text{A cm}^{-2}$)	V_{OC} (mV)	PCE (%)
TiO ₂ /N719 dye/CuCrO ₂	35	317	242	0.027
TiO ₂ /N719 dye/CuCrO ₂ :Zn	34	376	260	0.033
TiO ₂ /N719 dye/CuCrO ₂ :Mg	34	440	280	0.042

Table 2. Hall effect measurement results such as charge carrier concentration, hall mobility and resistivity.

Sample	CuCrO ₂	CuCrO ₂ :Zn (5%)	CuCrO ₂ :Mg (5%)
Charge carriers concentration (cm^{-3})	5.0×10^{16}	4.6×10^{17}	5.3×10^{18}
Hall mobility ($\text{cm}^2 \text{V}^{-1} \text{s}^{-1}$)	2.7	2.4	2.2
Resistivity ($\Omega \text{ cm}$)	46.3	5.7	0.5

**Figure 7.** (a) Variation of conversion efficiency as a function of time for the DSSC assembled with Mg-doped CuCrO₂ nanoparticles as solid-state electrolyte and (b) current density–voltage curve of solid-state DSSC with Mg-doped CuCrO₂ nanoparticles under different light intensities.

E_{∞} is the vacuum energy) is increased. The open-circuit voltage decay measurement shows slower recombination rate for the DSSC fabricated with Zn- and Mg-doped CuCrO₂ nanoparticles (see figure 6b). The slow recombination rate in the DSSCs made from doped CuCrO₂ nanoparticles can be attributed to the conductivity improvement in the CuCrO₂ nanoparticles. The calculated electron lifetime as a function of open-circuit voltage is shown in figure 6c. The DSSC made from Mg-doped CuCrO₂ nanoparticles has longer electron lifetime at open circuit voltage (about 39.5 ms) relative to that made from undoped (21.3 ms) and Zn-doped CuCrO₂ nanoparticles (28.9 ms). Zou *et al* [40] have reported similar results for FTO/TiO₂/CdTe/C structure with energy conversion efficiency of about 0.07% under AM1.5G

illumination (J_{SC} , V_{OC} and FF are 0.67 mA cm^{-2} , 0.65 V and 17%, respectively). Recently, Pavan *et al* [41] prepared the TiO₂/Cu₂O all-oxide heterojunction solar cells by spray pyrolysis method onto FTO glass substrates with short-circuit current density of 0.4 mA cm^{-2} and open-circuit voltage of about 350 mV. Furthermore, Yuhas *et al* [42] have observed photovoltaic properties in FTO/ZnO nanowire/Cu₂O nanoparticles structure with energy conversion efficiency of about 0.053% by using a TiO₂ blocking layer.

To study the long-term stability of the solid-state DSSC performance, the conversion efficiency of TiO₂/N719/Mg-doped CuCrO₂ device was monitored for a period of 10 days. Figure 7a exhibits the variation of conversion efficiency as a function of time. From the monitored conversion

Table 3. Photovoltaic parameters of the solid-state DSSC with Mg-doped CuCrO₂ nanoparticles as solid-state electrolyte under different light intensities.

Light intensity (mW cm ⁻²)	J_{SC} (mA cm ⁻²)	V_{OC} (mV)	FF (%)	PCE (%)	Shunt resistance (k Ω)	Series resistance (k Ω)
60	264	254	32.8	0.037	4.0	0.63
75	330	268	33.2	0.039	3.8	0.52
90	390	275	33.7	0.040	3.6	0.44
100	440	280	34.0	0.042	2.0	0.39

efficiency variation of the solid-state DSSC we can see that the performance of the DSSC shows no noticeable degradation and stays stable. From these results, it is expected that the CuCrO₂ as solid-state electrolyte is a promising candidate for constructing DSSCs with good durability.

To investigate the effect of intensity of light on the performance of the constructed solid-state DSSC, the light intensity has been varied. The obtained results are presented in figure 7b and table 3, which show that J_{SC} increases with increasing the intensity of incident light. As the intensity of light increases, the number of photons striking per unit area of the DSSC increases and consequently, the number of photogenerated charge carriers grows. As a result the efficiency of the solid-state DSSC increases, which can be attributed to the improvement of shunt and series resistances of the cell under high illumination.

4. Conclusions

We have investigated the influence of the TiO₂ nanoparticle size, the TiO₂ photoanode thickness and the solid-state electrolyte thickness on the photovoltaic properties of CuCrO₂-based solid-state DSSCs. We found that although the TiO₂ photoanode fabricated with the large-size particles does not have a large surface area for dye adsorption, but good electron transport and penetration of the large amount of CuCrO₂ nanoparticles in the porous structure lead to higher short-circuit current density and efficiency. We also improved the photocurrent, photovoltage and power conversion efficiency of the solid-state DSSCs by using doped CuCrO₂ nanoparticles. The power conversion efficiency increment in the DSSCs made from CuCrO₂ nanoparticles with divalent cations doping is attributed to the low electrical resistivity in comparison with the non-doped CuCrO₂ nanoparticles.

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